

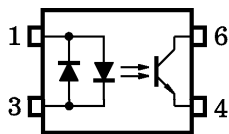
# TLP120

PROGRAMMABLE CONTROLLERS  
 AC/DC-INPUT MODULE  
 TELECOMMUNICATION

The TOSHIBA MINI FLAT COUPLER TLP120 is a small outline coupler, suitable for surface mount assembly. TLP120 consists of a photo transistor, optically coupled to two gallium arsenide infrared emitting diode connected inverse parallel, and can operate directly by AC input current.

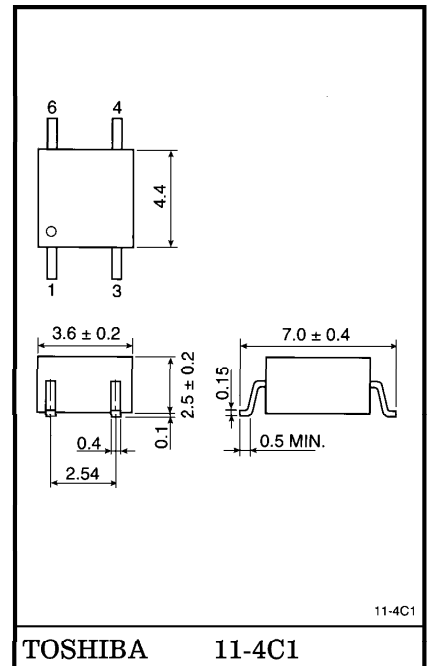
- Collector-Emitter Voltage : 80V (Min.)
- Current Transfer Ratio : 50% (Min.)  
     Rank GB : 100% (Min.)
- Isolation Voltage : 3750Vrms (Min.)
- UL Recognized : UL1577, File No. E67349

**PIN CONFIGURATIONS (TOP VIEW)**



- 1 : ANODE  
    CATHODE
- 3 : CATHODE  
    ANODE
- 4 : EMITTER
- 6 : COLLECTOR

Unit in mm



Weight : 0.09g

## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	$I_{F(RMS)}$	50	mA
	Forward Current Derating	$\Delta I_F / ^\circ C$	-0.7 (Ta $\geq$ 53°C)	mA / °C
	Pulse Forward Current	$I_{FP}$	1 (100 $\mu$ s pulse, 100pps)	A
	Reverse Voltage	$V_R$	5	V
	Junction Temperature	$T_j$	125	°C
DETECTOR	Collector-Emitter Voltage	$V_{CEO}$	80	V
	Emitter-Collector Voltage	$V_{ECO}$	7	V
	Collector Current	$I_C$	50	mA
	Collector Power Dissipation	$P_C$	150	mW
	Collector Power Dissipation Derating (Ta $\geq$ 25°C)	$\Delta P_C / ^\circ C$	-1.5	mW / °C
	Junction Temperature	$T_j$	125	°C
Storage Temperature Range		$T_{stg}$	-55~125	°C
Operating Temperature Range		$T_{opr}$	-55~100	°C
Lead Soldering Temperature		$T_{sol}$	260 (10s)	°C
Total Package Power Dissipation		$P_T$	200	mW
Total Package Power Dissipation Derating (Ta $\geq$ 25°C)		$\Delta P_T / ^\circ C$	-2.0	mW / °C
Isolation Voltage (Note 1)		$BV_S$	3750 (AC, 1min., R.H. $\leq$ 60%)	Vrms

(Note 1) Device considered a two terminal device : Pins 1, 3 shorted together and pins 4, 6 shorted together.

## RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V_{CC}$	—	5	48	V
Forward Current	$I_{F(RMS)}$	—	16	20	mA
Collector Current	$I_C$	—	1	10	mA
Operating Temperature	$T_{opr}$	-25	—	85	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	$V_F$	$I_F = \pm 10\text{mA}$	1.0	1.15	1.3	V
	Capacitance	$C_T$	$V = 0, f = 1\text{MHz}$	—	60	—	pF
DETECTOR	Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 0.5\text{mA}$	80	—	—	V
	Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	$I_E = 0.1\text{mA}$	7	—	—	V
	Collector Dark Current	$I_{CEO}$	$V_{CE} = 48\text{V}$	—	10	100	nA
			$V_{CE} = 48\text{V}, T_a = 85^\circ\text{C}$	—	2	50	$\mu\text{A}$
Capacitance (Collector to Emitter)	$C_{CE}$	$V = 0, f = 1\text{MHz}$	—	10	—	pF	

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	$I_C / I_F$	$I_F = \pm 5\text{mA}, V_{CE} = 5\text{V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	$I_C / I_{F(\text{sat})}$	$I_F = \pm 1\text{mA}, V_{CE} = 0.4\text{V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 2.4\text{mA}, I_F = \pm 8\text{mA}$ $I_C = 0.2\text{mA}, I_F = \pm 1\text{mA}$ Rank GB	—	—	0.4	V
			—	0.2	—	
			—	—	0.4	
Off-State Collector Current	$I_{C(\text{off})}$	$V_F = \pm 0.7\text{V}, V_{CE} = 48\text{V}$	—	1	10	$\mu\text{A}$
CTR Symmetry	$I_{C(\text{ratio})}$	$I_C (I_F = -5\text{mA}) / I_C (I_F = 5\text{mA})$	0.33	1	3	—

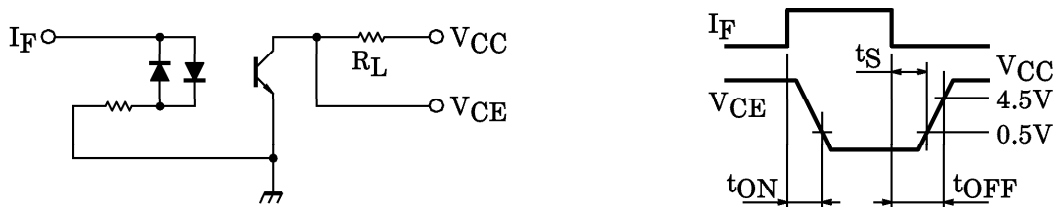
ISOLATION CHARACTERISTICS (Ta = 25°C)

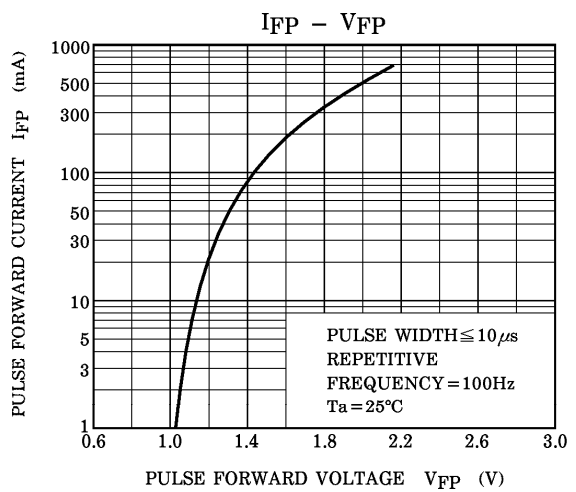
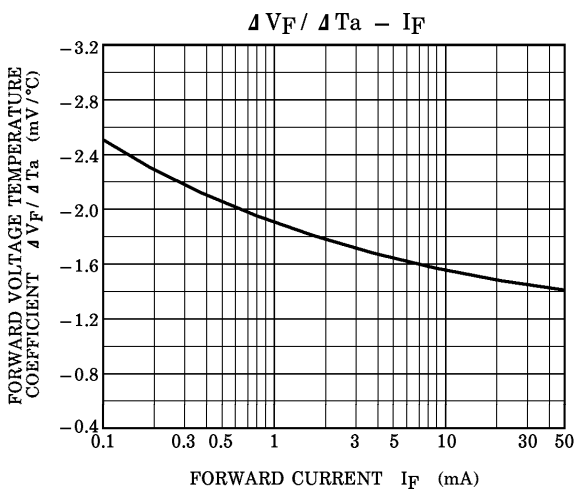
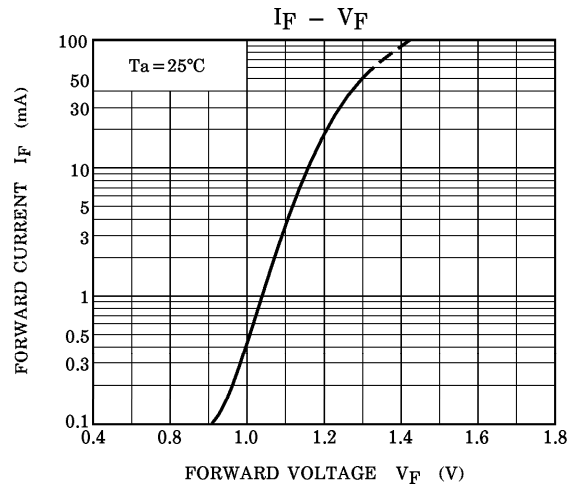
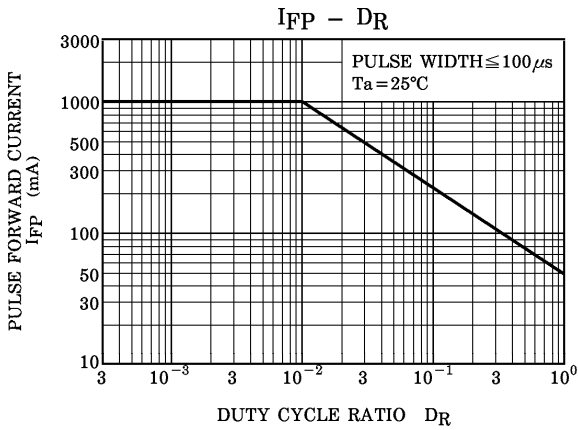
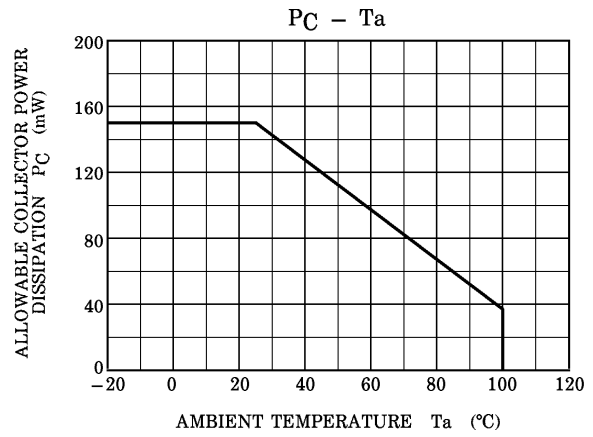
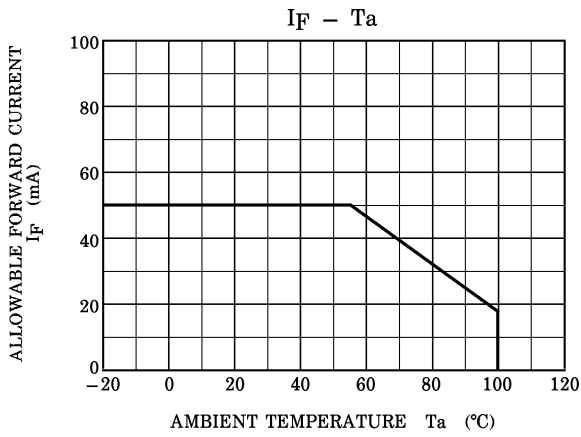
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance (Input to Output)	$C_S$	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation Resistance	$R_S$	$V_S = 500\text{V}, \text{R.H.} \leq 60\%$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation Voltage	$BV_S$	AC, 1 minute	3750	—	—	$V_{\text{rms}}$
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	$V_{\text{dc}}$

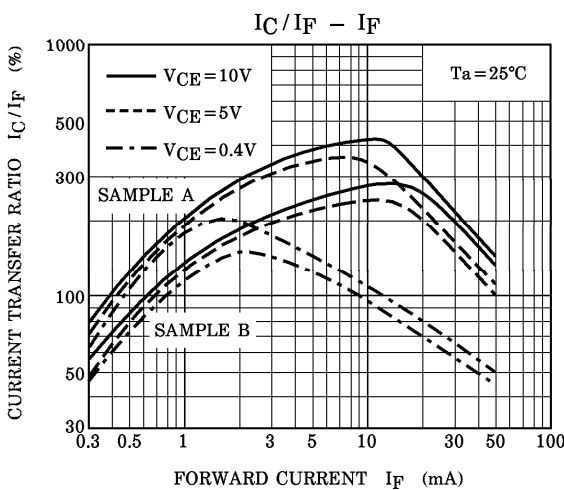
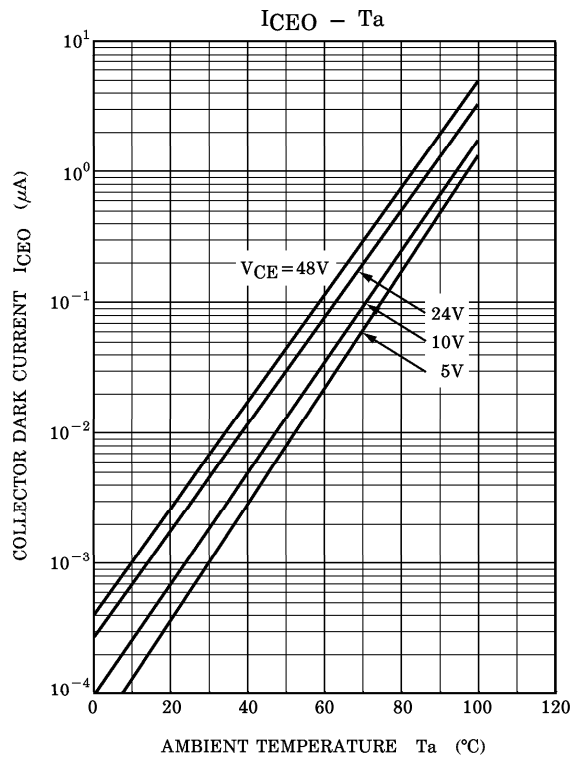
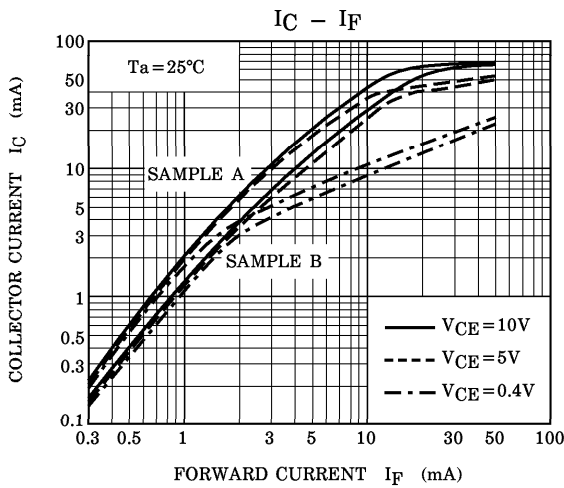
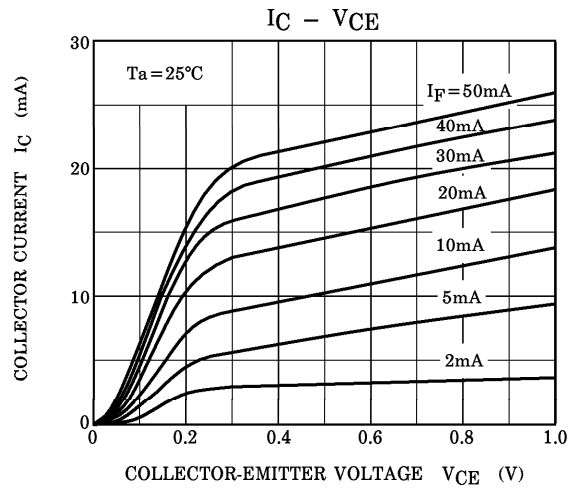
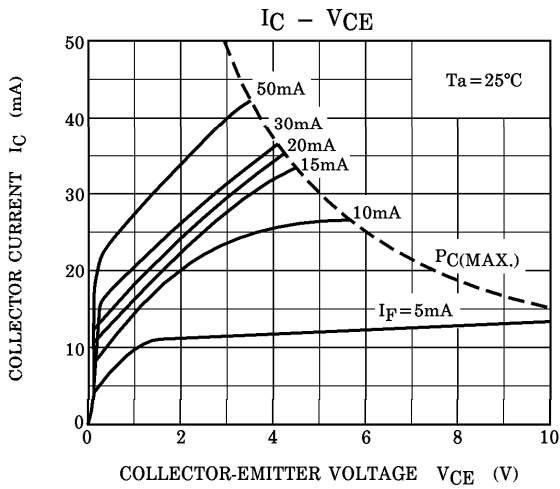
SWITCHING CHARACTERISTICS (Ta = 25°C)

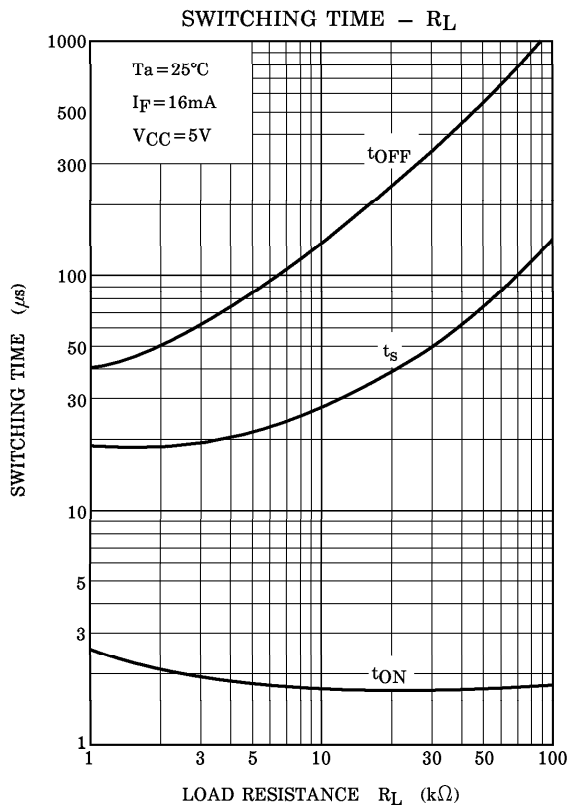
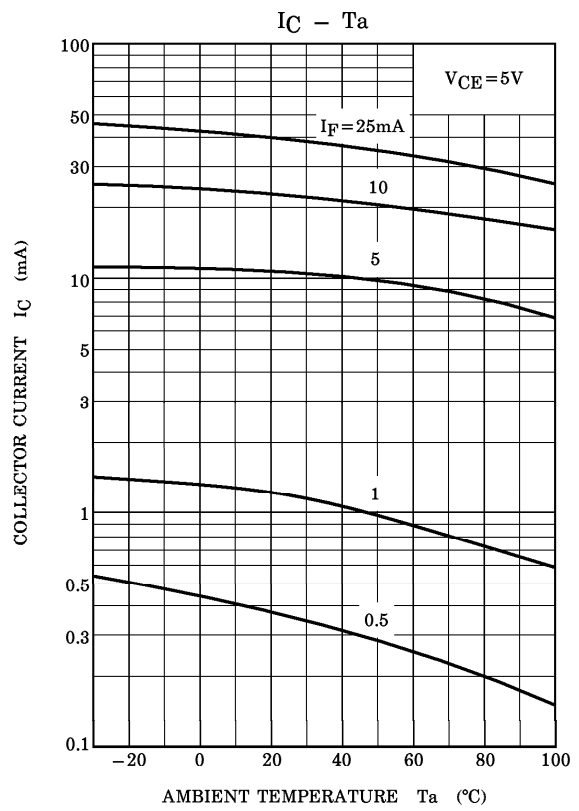
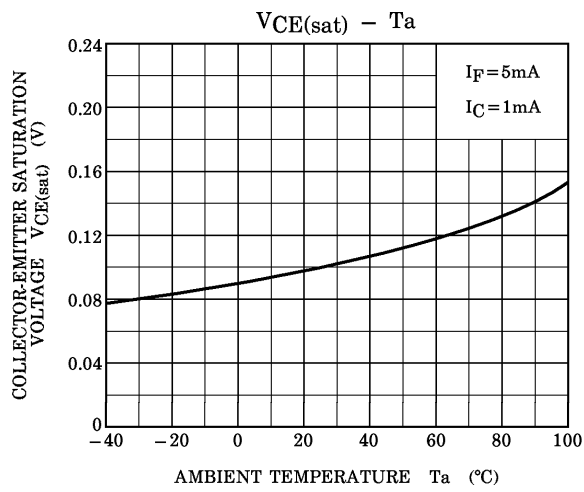
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Rise Time	$t_r$	$V_{CC} = 10V, I_C = 2mA$ $R_L = 100\Omega$	—	2	—	$\mu S$
Fall Time	$t_f$		—	3	—	
Turn-on Time	$t_{on}$		—	3	—	
Turn-off Time	$t_{off}$		—	3	—	
Turn-on Time	$t_{ON}$	$R_L = 1.9k\Omega$ (Fig.1) $V_{CC} = 5V, I_F = \pm 16mA$	—	2	—	$\mu S$
Storage Time	$t_s$		—	25	—	
Turn-off Time	$t_{OFF}$		—	40	—	

Fig.1 SWITCHING TIME TEST CIRCUIT









**RESTRICTIONS ON PRODUCT USE**

000707EBC

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.